



**APPLICATION DATA SHEET**

Electronic Version v14

Stylesheet Version v14.0

<b>Title of Invention</b>	BIPOLAR JUNCTION TRANSISTOR AND FABRICATING METHOD		
Application Type :		regular, utility	
Attorney Docket Number :		NAUP0486USA3	
Correspondence address:			
Customer Number:	027765		
Continuing Data:			
This is a Continuation of US application number 10/064,051, filed 2002-06-05 , now PENDING.			
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